Hit Count Set Name



Freeform Search

Database:	US Pro JPO A EPO A Derve	ents Full-Text Databa -Grant Publication Frostracts Database ostracts Database ostracts Database of World Patents Inde	ull-Text Database	<u> </u>		
Term:	13 and	i 14				
Display:		Oocuments in <u>Disp</u>			ith Number	1
Generate	: O Hit	List ③ Hit Coun	t O Side by Sid	e O Image		ı
***************************************	Searc	ch Clear	Help Log	gout Inter	rupt	
M	ain Menu	Show S Numbers	Edit S Numbers	Preferences	Cases	

Search History

DATE: Wednesday, February 13, 2002 Printable Copy Create Case

Set Name side by side	Query	Hit Count	Set Name result set
DB=US	SPT,PGPB,JPAB,EPAB,DWPI,TDBD; PLUR=YES; OP=OR		
L5	13 and 14	7	<u>L5</u>
<u> </u>	organ\$3 or polymer\$4	2232405	<u>L4</u>
<u>L3</u>	11 and 12	47	<u>L3</u>
<u>1.2</u>	cdte or (cadmium adj telluride)	6215	<u>L2</u>
<u>L1</u>	((438/795 438/796 438/797 438/798 438/799)!.CCLS.)	2364	<u>L1</u>

END OF SEARCH HISTORY

ţ

WEST

Generate Collection

Print

Search Results - Record(s) 1 through 7 of 7 returned.

1. Document ID: US 5937318 A

L5: Entry 1 of 7

File: USPT

Aug 10, 1999

US-PAT-NO: 5937318

DOCUMENT-IDENTIFIER: US 5937318 A

TITLE: Monocrystalline three-dimensional integrated circuit

Full | Title | Citation | Front | Review | Classification | Date | Reference | Sequences | Attachments | Claims | KMC |
Draw, Desc | Image |

2. Document ID: US 5714404 A

L5: Entry 2 of 7

File: USPT

Feb 3, 1998

US-PAT-NO: 5714404

DOCUMENT-IDENTIFIER: US 5714404 A

TITLE: Fabrication of polycrystalline thin films by pulsed laser processing

Full | Title | Citation | Front | Review | Classification | Date | Reference | Sequences | Attachments | Claims | KWC |
Draw Desc | Image |

3. Document ID: US 5578502 A

L5: Entry 3 of 7

File: USPT

Nov 26, 1996

US-PAT-NO: 5578502

DOCUMENT-IDENTIFIER: US 5578502 A

TITLE: Photovoltaic cell manufacturing process

Full | Title | Citation | Front | Review | Classification | Date | Reference | Sequences | Attachments | Claims | KWIC |
Draw Desc | Image |

4. Document ID: US 5252499 A

L5: Entry 4 of 7

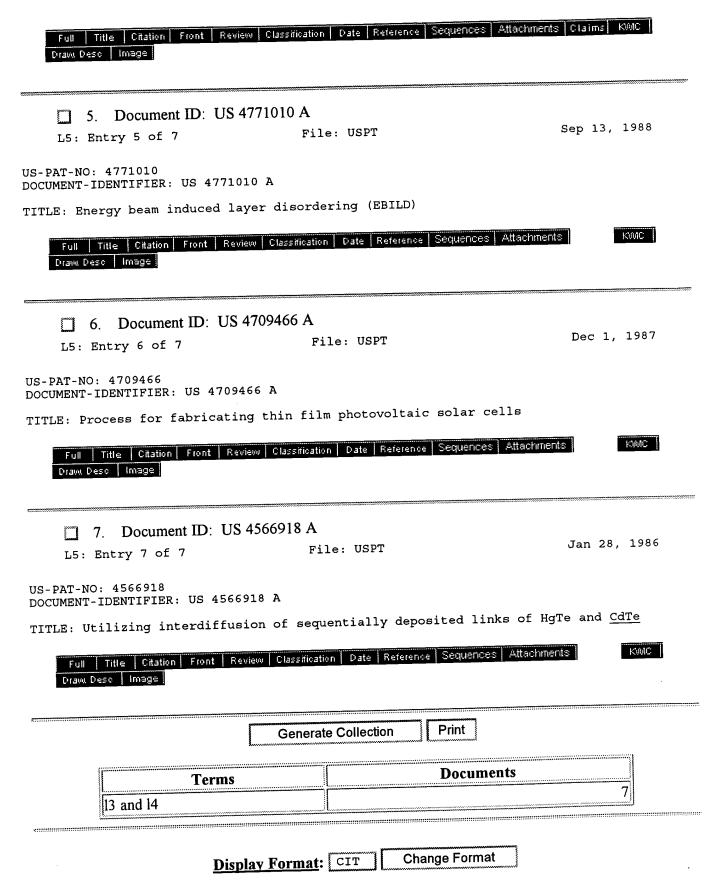
File: USPT

Oct 12, 1993

PAT-NO: 5252499

UMENT-IDENTIFIER: US 5252499 A

\: Wide band-gap semiconductors having low bipolar resistivity and method of ion



Previous Page Next Page



Freeform Search

Database:	US Patents Full-Text Database US Pre-Grant Publication Full-To JPO Abstracts Database EPO Abstracts Database Derwent World Patents Index IBM Technical Disclosure Bulleti		
Term: Display:	15 and 16 100 Documents in Display	Format: CTT Star	ting with Number 1
• •	S	***************************************	
Generate:	O Hit List O Hit Count O	Side by Side O 1ma	ge
***************************************	Search Clear He	elp Logout	Interrupt
Mai	in Menu Show S Numbers Ed	it S Numbers Preferer	ces Cases

Search History

DATE: Wednesday, February 13, 2002 Printable Copy Create Case

Set Name side by side	Query	Hit Count	Set Name result set	
DB=USPT,PGPB,JPAB,EPAB,DWPI,TDBD; PLUR=YES; OP=OR				
<u>L8</u>	15 and 16	30	<u>L8</u>	
<u>L7</u>	L6	118999	<u>L7</u>	
<u>L6</u>	photovolta\$4 or solar	118999	<u>L6</u>	
<u>L5</u>	11 and 12 and 14	96	<u>L5</u>	
<u>L4</u>	laser	553825	<u>L4</u>	
<u>L3</u>	11 same 12	16	<u>L3</u>	
<u>L2</u>	cdte or (cadmium adj telluride)	6215	<u>L2</u>	
<u>L1</u>	pen or pet or terephthalate or naphthalate	229187	<u>L1</u>	

END OF SEARCH HISTORY

benzyl alc. 36.7% was screen printed on the sintered CdS film, heated at 400.degree. for 1 h, and at 620.degree. in N for 1 h to form a sintered CdTe film. A C-Ag electrode and a Ag or In electrode were then formed on the CdTe and CdS films, resp., to form a solar cell. The sintered layers showed no cracks and had accurate patterning, and the prepd. cell had an output voltage of 0.8 V. cadmium sulfide solar cell; telluride cadmium solar cell; polymethyl methacrylate solar cell manuf Photoelectric devices, solar ΙT (cadmium sulfide-cadmium telluride, screen printing in manuf. of) 9011-14-7 25087-26-7 ΙT RL: USES (Uses) (in manuf. of cadmium sulfide-cadmium telluride solar cells) 1306-25-8P, preparation ΙT RL: PREP (Preparation) (photoelec. solar cells from junctions of cadmium sulfide and, screen printing in manuf. of) 1306-23-6P, preparation IT RL: PREP (Preparation) (photoelec. solar cells from junctions of cadmium telluride and, screen printing in manuf. of) ANSWER 20 OF 26 CA COPYRIGHT 2002 ACS L12 105:118209 CA AN Solar-cell module ΤI Nakano, Akihiko; Ikegami, Seiji; Matsuoka, Naoki; Ijichi, Ichiro IN Matsushita Electric Industrial Co., Ltd., Japan; Nitto Electric Industrial PA Co., Ltd. Jpn. Kokai Tokkyo Koho, 5 pp. SO CODEN: JKXXAF Patent DT Japanese LА ICM H01L031-04 TC 52-2 (Electrochemical, Radiational, and Thermal Energy Technology) Section cross-reference(s): 38 FAN.CNT 1 APPLICATION NO. DATE KIND DATE PATENT NO. _____ _____ _____ JP 1984-232647 19841105 JP 61110472 A2 19860528 PΤ A solar cell module has a protection film of an AΒ insulation screen and an Al foil attached by a thermoplastic resin to the backside of solar cells formed on a glass substrate. The resin is a mixt. of an .alpha., .beta.-unsatd. carboxylic acid-graft modified polyethylene (or ethylene-unsatd. ester copolymer) and an arom. vinyl hydrocarbon polymer or poly(vinyl halide) or a mixt. of ethylene-vinyl acetate copolymer and acrylic acid-graft polystyrene. Thus, a 85-.mu. poly(ethylene terephthalate) screen and an Al foil were bonded to a CdS-CdTe solar-cell module with ethylene-vinyl acetate copolymer layers to form a protection film. After a 1000-h exposure to 75.degree. and 95% relative humidity, the performance of the module decreased <4%. cadmium sulfide solar cell; telluride stcadmium solar cell; ethylene copolymer solar cell protection; vinyl acetate copolymer solar cell Photoelectric devices, solar ΙT (cadmium sulfide-cadmium telluride or silicon, thermoplastic binder for protection films for) 9003-53-6 IT

RL: USES (Uses) (binder mixt. contg., for solar-cell protection films) IT 24937-78-8 RL: USES (Uses) (binders, for solar-cell proteiction films) IT 26713-18-8 RL: USES (Uses) (graft, binder mixt. from polystyrene and, for solarcell protection films) L12 ANSWER 21 OF 26 CA COPYRIGHT 2002 ACS 102:206636 CA ΑN TТ Solar cell Nakano, Akihiko; Matsumoto, Hitoshi; Uda, Hiroshi; Komatsu, Yasumasa; IN Kuribayashi, Kiyoshi; Ikegami, Seiji Matsushita Electric Industrial Co., Ltd., Japan PΑ Ger. Offen., 23 pp. SO CODEN: GWXXBX DT Patent LΑ German IC ICM H01L031-04 ICS C03C017-32; C03C017-38 52-2 (Electrochemical, Radiational, and Thermal Energy Technology) Section cross-reference(s): 38 FAN.CNT 1 PATENT NO. APPLICATION NO. DATE KIND DATE DE 3428775 A1 19850228 DE 1984-3428775 19840801 PΙ JP 60032352 A2 19850219 JP 1983-141333 19830801 19830801 PRAI JP 1983-141333 A solar-cell module comprises a glass substrate, a solar-cell section from several thin-layer, amorphous Si or Group 12/16 (IIB/VIA), solar cells, which are formed by retaining an edge region along the substrate edge, and a resin layer applied on the solar-cell section and the edge-region of the substrate. The module has also a resin back-side protection layer, which covers the cell section and the edge region of the substrate. The resin is preferably a fluoropolymer selected from compds. contg. perfluoroalkylene groups and active H atoms. Thus, on a 900-cm2 glass substrate, a CdS/CdTe solar-cell section was formed retaining an edge region along the substrate edge. As backside protection layer a resin-coated Al foil with a poly(vinyl butyral) adhesive (0.38 mm) was used. A test module with an edge-region width of 6.5 mm showed only very small changes in appearance and in photoelec. properties after immersing for 24 h in water at 100.degree. and then in water at 0.degree. for 24 h. cadmium sulfide solar cell module; copper sulfide solar cell module; silicon solar cell module; polyvinyl butyral solar cell module Photoelectric devices, solar IT (module, manuf. of and adhesives and coating materials for) IT Epoxy resins, uses and miscellaneous Rubber, silicone, uses and miscellaneous Siloxanes and Silicones, uses and miscellaneous Urethane polymers, uses and miscellaneous RL: USES (Uses) (photoelec. solar-cell module contg., cadmium sulfide-cadmium telluride) Phenolic resins, uses and miscellaneous IT RL: USES (Uses) (resol, photoelec. solar-cell, module contg.,

cadmium sulfide-cadmium telluride) IT Vinyl acetal polymers RL: USES (Uses) (butyrals, adhesive, photoelec. solar-cell module contg., cadmium sulfide-cadmium telluride 1306-25-8P, preparation IT RL: PREP (Preparation) (photoelec. solar cell from heterojunction of cadmium sulfide and, manuf. of module of) ΙT 1306-23-6P, preparation RL: PREP (Preparation) (photoelec. solar cell from heterojunction of cadmium telluride and, manuf. of module of) IT 108-80-5D, adduct of hexamethylene diisocyanate 822-06-0D, adduct of cyanuric acid 86472-86-8 86923-92-4 96352-11-3 96352-16-8 96352-68-0 96352-85-1 96352-98-6 96353-84-3 96353-86-5 96353-87-6 RL: USES (Uses) (photoelec. solar-cell module contg., cadmium sulfide-cadmium telluride) L12 ANSWER 22 OF 26 CA COPYRIGHT 2002 ACS AN 102:206554 CA TТ Applications of electrogenerated conducting polymers in electrochemical photovoltaic cells AU Noufi, Rommel Sol. Electr. Convers. Res. Div., Sol. Energy Res. Inst., Golden, CO, CS 80401, USA SO Conf. Rec. IEEE Photovoltaic Spec. Conf. (1982), 16th, 1293-8 CODEN: CRCNDP; ISSN: 0160-8371 DTJournal LΑ English CC 52-2 (Electrochemical, Radiational, and Thermal Energy Technology) Section cross-reference(s): 38, 72 AΒ The electrochem. generated conducting polypyrrole PP [30604-81-0] films protect n-type semiconductor photoelectrodes from degrdn. while permitting electron exchange between the semiconductor and the electrolyte. The performance characteristics and stability of PP-covered GaAs, Si, CdTe, CdSe, and CdS photoelectrodes are discussed. ST polypyrrole coating photoelectrochem electrode; silicon polypyrrole photoelectrochem electrode; sulfide cadmium polypyrrole photoelectrochem electrode; selenide cadmium polypyrrole photoelectrochem electrode; gallium arsenide polypyrrole photoelectrochem electrode; cadmium telluride polypyrrole photoelectrochem electrode TΤ Electrodes (photoelectrochem., polypyrrole-coated, performance and stability of) IT 30604-81-0 RL: USES (Uses) (electrodes coated with, photoelectrochem., performance and stability 1303-00-0, uses and miscellaneous 1306-23-6, uses and miscellaneous IΤ 1306-24-7, uses and miscellaneous 1306-25-8, uses and miscellaneous 7440-21-3, uses and miscellaneous RL: USES (Uses) (electrodes from polypyrrole-coated, photoelectrochem., performance and stability of) L12 ANSWER 23 OF 26 CA COPYRIGHT 2002 ACS 100:54608 CA AN Photoelectrochemical cells for conversion of solar energy to electricity ΤI IN Skotheim, Terje

PA

U.S., 11 pp. Cont.-in-part of U.S. 4,352,868. CODEN: USXXAM

 $\mathtt{D}\mathbf{T}$ Patent

LA IC English H01M006-36

- L13 ANSWER 5 OF 5 INSPEC COPYRIGHT 2002 IEE
- AN 1981:1722104 INSPEC DN A81070652; B81039115
- TI A tandem **photovoltaic** cell using a thin-film **polymer** electrolyte.
- AU Skotheim, T. (Lab. d'Electrochimie Interfaciale, CNRS, Meudon-Bellevue, France)
- SO Applied Physics Letters (1 May 1981) vol.38, no.9, p.712-14. 17 refs. CODEN: APPLAB ISSN: 0003-6951
- DT Journal
- TC New Development; Practical
- CY United States
- LA English
- AB A tandem photovoltaic cell has been fabricated using a thin-film plastic electrolyte to connect in optical and electrical series an n-type CdS thin-film and a p-type CdTe single crystal. The electrolyte was a thin film of poly(ethylene oxide) with a polysulfide redox couple. An open circuit voltage of 625 mV and a short-circuit current of 35 mu A/cm2 were obtained under illumination of 100 mW/cm2 with a xenon lamp. The cell output in the present configuration is limited by the series resistance and insufficient band bending in the semiconductor electrodes due to unfavorable resistance matching of the components.
- CC A8630J Photoelectric conversion: solar cells and arrays; A8630K Photoelectrochemical conversion; B8420 Solar cells and arrays
- CT CADMIUM COMPOUNDS; ELECTROLYTES; II-VI SEMICONDUCTORS; PHOTOELECTROCHEMICAL CELLS; PHOTOVOLTAIC CELLS; SOLAR CELLS
- ST tandem photovoltaic cell; thin-film polymer electrolyte
 ; n-type CdS thin-film; p-type CdTe single crystal;
 poly(ethylene oxide); polysulfide redox couple; open circuit voltage;
 short-circuit current; cell output; series resistance; band bending
- ET Cd*S; CdS; Cd cp; cp; S cp; Cd*Te; Cd sy 2; sy 2; Te sy 2; CdTe; Te cp

(1) Dieter, B; US 5304499 A 1994 CA (2) Hu, H; JOURNAL OF CRYSTAL GROWTH V152(3), P150 CA (3) Kogyo Gijutsuin; JP 58194377 A 1983 CA (4) Nishiwaki, H; SOLAR ENERGY MATERIALS AND SOLAR CELLS V37(3/04), P295 (5) Nissha Printing Co Ltd; JP 05090624 A 1993 CA (6) Sumitomo Bakelite Co Ltd; JP 61168271 A 1986 CA (7) Teijin Ltd; JP 62084568 A 1987 L12 ANSWER 7 OF 26 CA COPYRIGHT 2002 ACS 131:76094 CA Nanoparticle-based contacts to CdTe ΤI Schulz, D. L.; Ribelin, R.; Curtis, C. J.; King, D. E.; Ginley, D. S. ΑU CS National Renewable Energy Laboratory, Photovoltaic and Electronic Materials Center and Basic Sciences Center, Golden, CO, 80401-3393, USA SO Mater. Res. Soc. Symp. Proc. (1999), 536(Microcrystalline and Nanocrystalline Semiconductors--1998), 407-411 CODEN: MRSPDH; ISSN: 0272-9172 PB Materials Research Society DTJournal LΑ English CC 52-2 (Electrochemical, Radiational, and Thermal Energy Technology) AΒ Our team has been investigating the use of particle-based contacts in CdTe solar cell technologies. Toward this end, particles of Cu-doped HgTe (Hg-Cu-Te) and SbTe have been applied as contacts to CdTe/CdS/SnO2 heterostructures. These metal telluride materials were characterized by std. methods. Hg-Cu-Te particles in graphite electrodag contacts produced CdTe solar cells with efficiencies above 12% and series resistance (Rse) of 6 .OMEGA. or less. Metathesis prepn. of Cu(I) and Cu(II) tellurides (i.e., Cu2Te and CuTe, resp.) were attempted as a means of characterizing the valence state of Cu in the Hg-Cu-Te ink. For SbTe contacts to CdTe, open circuit voltages (Vocs) in excess of 800 mV were obsd., however, efficiencies were limited to 9%; perhaps a consequence of the marked increase in the Rse (i.e., >20 .OMEGA.) in these non-graphite contg. contacts. Acetylene black was mixed into the methanolic SbTe colloid as a means of reducing Rse, however, no improvement in device properties was obsd. STcadmium telluride solar cell; nanoparticle based elec contact solar cell IT Acrylic polymers, uses RL: TEM (Technical or engineered material use); USES (Uses) (electrodag contg.; nanoparticle-based contacts to CdTe solar cell technologies) IT Electric contacts Solar cells (nanoparticle-based contacts to CdTe solar **cell** technologies) IT Carbon black, uses RL: MOA (Modifier or additive use); USES (Uses) (nanoparticle-based contacts to CdTe solar cell technologies) IT 67-56-1, Methanol, uses RL: TEM (Technical or engineered material use); USES (Uses) (Br soln. of, etchant; nanoparticle-based contacts to CdTe solar cell technologies) IT 7726-95-6, Bromine, uses RL: TEM (Technical or engineered material use); USES (Uses) (MeOH soln.. etchant; nanoparticle-based contacts to CdTe solar cell technologies) ΙT 7440-50-8, Copper, uses RL: MOA (Modifier or additive use); USES (Uses) (dopant; nanoparticle-based contacts to CdTe solar

cell technologies) 1306-23-6, Cadmium sulfide, uses 1306-25-8, Cadmium - IT telluride, uses 7782-42-5, Graphite, uses 12067-31-1, Antimony telluride sbte 12068-90-5, Mercury telluride hgte 18282-10-5, Tin dioxide RL: DEV (Device component use); USES (Uses) (nanoparticle-based contacts to CdTe solar cell technologies) ΙT 12019-23-7P, Copper telluride cute 12019-52-2P, Copper telluride cu2te RL: DEV (Device component use); SPN (Synthetic preparation); PREP (Preparation); USES (Uses) (nanoparticle-based contacts to CdTe solar cell technologies) L12 ANSWER 8 OF 26 CA COPYRIGHT 2002 ACS AN 130:40957 CA Curable polymer electrically conducting pastes, and electrodes TIand solar cells using them IN Ooya, Hirohisa PA Murata Mfg. Co., Ltd., Japan Jpn. Kokai Tokkyo Koho, 4 pp. SO CODEN: JKXXAF דית Patent LA Japanese TC ICM H01B001-20 ICS H01L031-0264 52-2 (Electrochemical, Radiational, and Thermal Energy Technology) CC Section cross-reference(s): 76 FAN.CNT 1 PATENT NO. KIND DATE APPLICATION NO. DATE -----PΙ JP 10302543 A2 19981113 JP 1997-107780 19970424 The pastes contain anion exchangers and silane coupling agents. AB electrodes and solar cells using the pastes are also claimed. The pastes showed good adhesion even at high temp. anion exchanger elec conducting paste electrode; silane coupling agent ST conducting paste electrode; solar cell electrode elec conducting paste TT Anion exchangers Coupling agents Electrically conductive pastes Photoelectric cell electrodes (elec. conducting pastes contg. anion exchangers and silane coupling agents for electrodes of solar cells) IT Silanes RL: DEV (Device component use); MOA (Modifier or additive use); USES (Uses) (elec. conducting pastes contg. anion exchangers and silane coupling agents for electrodes of solar cells) IT 2530-83-8, .gamma.-Glycidoxypropyltrimethoxysilane RL: DEV (Device component use); MOA (Modifier or additive use); USES (elec. conducting pastes contg. anion exchangers and silane coupling agents for electrodes of solar cells) IT 10361-43-0, Bismuth hydroxide 152761-81-4, Antimony hydroxide RL: MOA (Modifier or additive use); USES (Uses) (elec. conducting pastes contg. anion exchangers and silane coupling agents for electrodes of solar cells) ΙT 1306-23-6, Cadmium sulfide, uses 1306-25-8, Cadmium telluride, uses RL: DEV (Device component use); USES (Uses) (semiconductors; elec. conducting pastes contg. anion exchangers and

```
silane coupling agents for electrodes of solar cells
L12 ANSWER 9 OF 26 CA COPYRIGHT 2002 ACS
AN
     129:205144 CA
TI
     Photovoltaic structures based on polymer/semiconductor
     junctions
     Gamboa, S. A.; Nguyen-Cong, H.; Chartier, P.; Sebastian, P. J.; Calixto,
ΑIJ
     M. E.; Rivera, M. A.
CS
     Centro de Investigaciones en Energia Coordinacion de Solar-H2-Celdas de
     Combustible, CIE-UNAM, Temixco, Morelos, 62580, Mex.
SO
     Sol. Energy Mater. Sol. Cells (1998), 55(1-2), 95-104
     CODEN: SEMCEQ; ISSN: 0927-0248
PB
     Elsevier Science B.V.
DT
     Journal
LΑ
     English
CC
     52-2 (Electrochemical, Radiational, and Thermal Energy Technology)
     Section cross-reference(s): 38, 72
AΒ
     CdTe and CuInSe2 (CIS) thin films were electrodeposited and
     characterized for photovoltaic applications. Schottky
     barrier-type photovoltaic junctions were obtained using a
     heavily doped PMeT (poly-3-methylthiophene), prepd. by electropolymn.,
     displaying nearly metallic behavior, and semiconductors such as
     CdTe and CIS obtained by electrodeposition. The
     photovoltaic structures formed and studied are Mo/CIS/PMeT/grid
     and Mo/CdTe/PMeT/grid Schottky barrier junctions. Solar to
     elec. conversion efficiency of the order of 1% was obtained in the case of
     PMeT/CIS and PMeT/CdTe junctions.
ST
     solar cell polymer semiconductor junction;
     polymethylthiophene copper indium selenide solar cell;
     cadmium telluride polymethylthiophene solar
IΤ
     Electrodeposition
     Schottky solar cells
       Solar cells
        (photovoltaic structures based on polymer
        /semiconductor junctions)
     1306-25-8, Cadmium telluride, uses 7439-98-7,
     Molybdenum, uses
                       12018-95-0, Copper indium diselenide 84928-92-7,
     Poly-3-methylthiophene
     RL: DEV (Device component use); USES (Uses)
        (photovoltaic structures based on polymer
        /semiconductor junctions)
L12 ANSWER 10 OF 26 CA COPYRIGHT 2002 ACS
AN
     127:296265 CA
TI
     Thin-film photovoltaic device and its manufacture
ΙN
    Albright, Scot P.; Chamberlin, Rhodes
PA
     Photon Energy, Inc., USA
SO
    U.S., 17 pp.
    CODEN: USXXAM
DT
    Patent
LA
    English
    ICM H01L031-0384
IC
    ICS H01L031-072; H01L031-18
NCL 136250000
    52-2 (Electrochemical, Radiational, and Thermal Energy Technology)
CC
FAN.CNT 1
    PATENT NO.
                     KIND DATE
                                          APPLICATION NO. DATE
    _____
                     ____
                           -----
                                          -----
                           19971007
                                          US 1995-480452
    US 5674325
                                                           19950607
PΙ
                     Α
                    Α
    US 5868869
                           19990209
                                          US 1997-946365 19971007
```

PRAI US 1995-480452 19950607 The device comprises a film layer having particles of .ltorsim.30 .mu.msize held in an elec. insulating matrix material to decrease the potential for elec. shorting through the film layer. The film layer may be provided by depositing preformed particles on a surrogate substrate and binding the particles in a film-forming matrix material to form a flexible sheet with the film layer. The flexible sheet may be sepd. from the surrogate substrate and cut into flexible strips. A plurality of the flexible strips may be located adjacent to and supported by a common supporting substrate to form a photovoltaic module having a plurality of elec. interconnected photovoltaic cells. ST thin film photovoltaic cell manuf IT Polymers, uses RL: TEM (Technical or engineered material use); USES (Uses) (insulating matrix in manuf. of thin-film photovoltaic device) TΤ Solar cells (thin-film; manuf. of) 1306-23-6, Cadmium sulfide, uses 1306-25-8, Cadmium ΙT telluride, uses 12018-95-0, Copper indium diselenide RL: DEV (Device component use); USES (Uses) (thin-film photovoltaic device and its manuf.) L12 ANSWER 11 OF 26 CA COPYRIGHT 2002 ACS AN125:37994 CA ΤI Wet polymer electrolyte photoelectrochemical solar cells and their manufacture ΙN Takeuchi, Masataka Showa Denko Kk, Japan PΑ SO Jpn. Kokai Tokkyo Koho, 11 pp. CODEN: JKXXAF DΤ Patent LΑ Japanese IC ICM H01M014-00 ICS C08F020-34; C08L033-06; H01B001-06; H01L031-04 52-2 (Electrochemical, Radiational, and Thermal Energy Technology) CC FAN.CNT 1 PATENT NO. KIND DATE APPLICATION NO. DATE ______ -----JP 08088030 PΤ A2 19960402 JP 1994-273057 19941012 PRAI JP 1994-190061 19940719 The cells have a redox-able species contg. ion conductive material between an electrode pair with .gtoreq.1 electrode being a semiconductor, where the ion conductive material is a solid polymer electrolyte of (co)polymers of (meth)acryloyloxyalkyl carbamate ester CH2:CR1CO(OQ) zNHCO2R2 [R1 = H or Me; R2 = linear, branched, or cyclic org. chain contg. .gtoreq.1 oxyalkylene group; Q = -(CH2)x- or -(CHMe)y-; x andy = 0 or 1-5 integer but not both = 0; and z = 0 or 1-10 integer], (co) polymers of (meth)acryloyl(oxyalkyl) carbamate ester CH: CR1CO(OQ) zNHCO2(R3O)R4 [R3 = -CH2- or -CHMeCH2-; R4 = C1-10 alkyl group, -CONH(Q'O)wCOCH:CH2, or -CONH(Q'O)ICOCMe:CH2; Q' = -(CH2)x'-or-(CHMe)y'-; x' and y' = 0 or 1-5 integer but not both = 0; n = an integer; w and z = 0 or 1-10 integer], or (co)polymers of $CH2: CR1CO(OQ) \ zNHCO2 \ [(R6O) mCONHR5NHCO2] \ k \ (R3O) \ nR4 \ [R6 = -(CH2) \ 2-or$ -CHMeCH2-; R5 = C1-20 alkylene group, allylene group, arylene group, or oxyalkylene group; and m and k = integer]. The solar cells are prepd. by adding a mixt. contg. the monomers to a photoelec. solar cell structure and polymg. the monomer. photoelectrochem solar cell polymer STelectrolyte manuf 106769-84-0P, Cadmium selenide telluride (Cd(Se,Te)) ΙT

```
RL: DEV (Device component use); IMF (Industrial manufacture); PEP
      (Physical, engineering or chemical process); PREP (Preparation); PROC
      (Process); USES (Uses)
         (cadmium selenide telluride photoelectrodes for wet
         photoelectrochem. solar cells with polymer
         electrolytes)
 IT
      161518-46-3P
                    163186-25-2P
                                    177766-68-6P
      RL: DEV (Device component use); IMF (Industrial manufacture); PEP
      (Physical, engineering or chemical process); PREP (Preparation); PROC
      (Process); USES (Uses)
         (compns. and manuf. of polymer electrolytes for wet
        photoelectrochem. solar cells)
     108-32-7P, Propylene carbonate
IT
                                       7553-56-2P, Iodine, uses
                                                                  7681-82-5P,
     Sodium iodide, uses
                          13755-29-8P, Sodium fluoroborate
     RL: DEV (Device component use); IMF (Industrial manufacture); PEP
      (Physical, engineering or chemical process); PREP (Preparation); PROC
      (Process); USES (Uses)
         (compns. of polymer electrolytes for wet photoelectrochem.
        solar cells)
L12 ANSWER 12 OF 26 CA COPYRIGHT 2002 ACS
AN
     121:283459 CA
     Current status of EVA degradation in Si modules and interface stability in
TI
     CdTe/CdS modules
ΑU
     Czanderna, A. W.
     National Renewable Energy Laboratory, Measurements and Characterization
CS
     Branch, Golden, CO, 80401, USA
     AIP Conf. Proc. (1994), 306(12TH NREL PHOTOVOLTAIC PROGRAM REVIEW, 1993),
SO
     147-55
     CODEN: APCPCS; ISSN: 0094-243X
DT
     Journal; General Review
LΑ
     English
     52-0 (Electrochemical, Radiational, and Thermal Energy Technology)
CC
     Section cross-reference(s): 36
AB
     A review with 14 refs. of the goals, objectives, background, tech.
     approach, status, and accomplishments on the Photovoltaic Module
     Reliability Research Task. The accomplishments are reported on EVA
     polymer degrdn. in Si modules and on interface stability in
     CdTe/CdS modules. The modified EVA and potential EVA
     replacements, degrdn. mechanisms, efficiency losses from yellowed EVA, and
     equipment acquisitions are discussed. The stability of the SnO2/CdS
     interface and degrdn. at the CdTe/CdS interface are also
     described.
     review EVA degrdn silicon solar cell; cadmium
ST
     telluride cadmium sulfide photocell review
     Photoelectric devices, solar
TT
        (degrdn. of ethylene-vinyl acetate polymer in silicon
        solar cell modules and interface stability in
        cadmium sulfide/cadmium telluride
        solar cell modules)
IT
     7440-21-3, Silicon, uses
     RL: DEV (Device component use); USES (Uses)
        (degrdn. of ethylene-vinyl acetate polymer in silicon
        solar cell modules)
IT
     24937-78-8, EVA
     RL: DEV (Device component use); PRP (Properties); USES (Uses)
        (degrdn. of ethylene-vinyl acetate polymer in silicon
        solar cell modules)
ΙT
     1306-23-6, Cadmium sulfide, uses
                                        1306-25-8, Cadmium
     telluride, uses
     RL: DEV (Device component use); PRP (Properties); USES (Uses)
        (interface stability in cadmium sulfide/cadmium
```

telluride solar cell modules)

```
L12 ANSWER 13 OF 26 CA COPYRIGHT 2002 ACS
 AN
      119:230036 CA
      Cadmium telluride/doped poly(N-epoxypropylcarbazole)
 ΤI
      structure of a solid-state photovoltaic cell
 ΑU
      Pokhodenko, V. D.; Guba, N. F.
      L.V. Pisarzhevsky Institute of Physical Chemistry of the Ukrainian Academy
 CS
      of Sciences, Kiev, Ukraine
      Synth. Met. (1993), 60(1), 73-5
 SO
      CODEN: SYMEDZ; ISSN: 0379-6779
 DT
      Journal
      English
 LА
      52-2 (Electrochemical, Radiational, and Thermal Energy Technology)
 CC
      Section cross-reference(s): 38, 76
 AΒ
     A solid-state photovoltaic cell of polycryst. CdTe
     /doped poly(N-epoxypropylcarbazole)/Au sandwich structure attained energy
     conversion efficiency of .ltoreq.3.2%. The spectral sensitivity range of
     the cell spans the UV, visible, and near-IR. The cell is chem. stable
     during storage and under operation and is easy to fabricate.
 ST
     cadmium telluride conducting polymer
     photovoltaic cell; polyepoxypropylcarbazole cadmium
     telluride solar cell
     Photoelectric devices, solar
IΤ
        (cadmium telluride/poly(N-
        epoxypropylcarbazole)/gold, characteristics of)
IT
     Electric conductors, polymeric
        (poly(N-epoxypropylcarbazole), electrochem. oxidized, chem. stability
        of)
ΙT
     55774-96-4, Poly(N-epoxypropylcarbazole)
     RL: USES (Uses)
        (photoelec. solar cells, with cadmium
        telluride and gold, characteristics of)
IT
     7440-57-5, Gold, uses
     RL: USES (Uses)
        (photoelec. solar cells, with cadmium
        telluride and poly(N-epoxypropylcarbazole), characteristics of)
IT
     1306-25-8, Cadmium telluride (CdTe), uses
     RL: USES (Uses)
        (photoelec. solar cells, with poly(N-
        epoxypropylcarbazole) and gold, characteristics of)
L12 ANSWER 14 OF 26 CA COPYRIGHT 2002 ACS
AN
     117:115199 CA
TI
     Solar-cell arrays and their manufacture
IN
     Matsuyama, Fukateru
PA
     Canon K. K., Japan
     Jpn. Kokai Tokkyo Koho, 9 pp.
SO
     CODEN: JKXXAF
DT
     Patent
LΑ
    Japanese
IC
    ICM H01L031-04
    52-2 (Electrochemical, Radiational, and Thermal Energy Technology)
CC
FAN.CNT 1
    PATENT NO.
                     KIND DATE
                                         APPLICATION NO. DATE
                     ----
                                          -----
                  A2 19920417
    JP 04116986
                                          JP 1990-235892
                                                           19900907
    JP 2986875
                     B2 19991206
    The arrays has solar cells comprising a semiconductor
    layer held between a top electrode and a bottom electrode, connected to
    each other, the cells are covered at their ends or whole surface with an
    insulator and the elec. conductor layer connecting a top electrode and a
```

bottom electrode of 2 neighboring cells covers the insulator between the cells. The insulator may be a polymer or an inorg. material, the conductor may be a conductive polymer and/or a metal, and the semiconductor may be amorphous Si. The arrays are prepd. by forming patterned semiconductor and top electrode layers on bottom electrodes leaving part of the bottom electrodes exposed, forming insulator films to cover the ends or whole surface of the cells, removing the insulator films from part of a top electrode and a bottom electrode of 2 neighboring cells, and forming conductor layers to connect the exposed electrode areas. silicon solar cell array Epoxy resins, uses Polyimides, uses Siloxanes and Silicones, uses RL: USES (Uses) (elec. insulator, solar cells covered with, manuf. of arrays of) Electric insulators and Dielectrics (photoelec. solar cells covered with, manuf. of arrays of) Photoelectric devices, solar (silicon and cadmium sulfide-cadmium telluride, arrays, manuf. of) 12033-60-2, Silicon nitride (SiN) RL: USES (Uses) (elec. insulator, solar cells covered with, manuf. of arrays of) 7440-21-3P, Silicon, uses RL: PREP (Preparation); USES (Uses) (photoelec. solar cells, arrays, with elec. insulators among unit cells, manuf. of) ANSWER 15 OF 26 CA COPYRIGHT 2002 ACS L12114:146955 CA Solar cells having coated light-incident side Omura, Kuniyoshi; Suyama, Naoki; Hibino, Takeshi; Murozono, Mikio Matsushita Electric Industrial Co., Ltd., Japan Jpn. Kokai Tokkyo Koho, 3 pp. CODEN: JKXXAF Patent Japanese ICM H01L031-04 52-2 (Electrochemical, Radiational, and Thermal Energy Technology) Section cross-reference(s): 38 FAN.CNT 1 PATENT NO. KIND DATE APPLICATION NO. DATE -----JP 02177573 A2 19900710 JP 1988-334460 19881228 The solar cells have a glassy layer of resin mixed with inorg. powder on their light-incident side. Preferably, the solar cells contain 2 layers of semiconductor compds. (CdS or compd. contg. Cd and S, and CdTe or compd. contg. Cd and Te), electrodes, and a transparent glass coated with the resin mixt. at the light-incident side. The inorg. powder is selected from SiO2 and TiO2 at <50 wt. % of the resin. The coating may be applied in a required pattern. The coating gives the solar cells better appearance, decreases reflection loss of the cells, and makes cutting of glass easier when sepg. solar cells made on a common glass substrate,. solar cell resin silica coating; titania resin coating solar cell

)

ST

ΙT

ΙT

IT

ΙT

IT

ΑN

TΙ

IN

PA

SO

DT

LΑ

IC

CC

PΙ

AB

ST

Photoelectric devices, solar

```
(cadmium sulfide-cadmium telluride, with
         light-incident side coated with inorg. powder-contg. resin films)
      7631-86-9, Silica, uses and miscellaneous 13463-67-7, Titania, uses and
 ΙT
      miscellaneous
      RL: USES (Uses)
          (solar cells with polymer layers contg.)
 L12 ANSWER 16 OF 26 CA COPYRIGHT 2002 ACS
 AN
      114:125844 CA
 ΤI
      Solar cell modules
 IN
      Nakano, Akihiko
 PA
      Matsushita Electric Industrial Co., Ltd., Japan
 SO
      Jpn. Kokai Tokkyo Koho, 7 pp.
      CODEN: JKXXAF
 DТ
      Patent
 LΑ
      Japanese
 IC
      ICM H01L031-04
      52-2 (Electrochemical, Radiational, and Thermal Energy Technology)
 CC
 FAN.CNT 1
      PATENT NO.
                     KIND DATE
                                           APPLICATION NO. DATE
      -----
 PΙ
      JP 02170475
                      A2 19900702
                                           JP 1988-324125
                                                           19881222
     The modules have Group II chalcogenide or Group II chalcogenide/Group
     I-Group III chalcogenide semiconductors sealed in a package, which has an
     org. polymer or hydrophobic porous org. material attached to or
     a porous inorg material-org. material mixt. filled in its holes.
     polymer may be a silicon resin or a polyolefin, the porous org.
     material may be a fluoropolymer tape, and the filler may be sintered C
     mixed with wax or porous inorg. oxides. This structure allows O to
     permeate into the modules to prevent deterioration of the modules.
     solar cell module oxygen permeable; silicone resin
 ST
     solar cell module; polyolefin solar
     cell module; fluoropolymer solar cell module;
     carbon wax solar cell module; oxide inorg
     solar cell module; chalcogenide solar
     cell module
     Photoelectric devices, solar
        (cadmium sulfide-cadmium telluride and
        cadmium sulfide-copper indium selenide, modules,
        oxygen-permeable packaging materials for)
IT
     Fluoropolymers
     Rubber, silicone, uses and miscellaneous
     RL: USES (Uses)
        (solar cell modules with packaging materials of
        oxygen-permeable)
ΙT
     Waxes and Waxy substances
     RL: USES (Uses)
        (solar cell modules with packaging oxygen-permeable
        materials contq.)
     9002-88-4, Polyethylene
IT
                              25068-26-2, Poly(4-methyl pentene-1
     RL: USES (Uses)
        (solar cell modules with packaging materials of
        oxygen-permeable)
IT
     1344-28-1, Alumina, uses and miscellaneous 7440-44-0, Carbon, uses and
     miscellaneous
     RL: USES (Uses)
        (solar cell modules with packaging oxygen-permeable
       materials contg.)
L12 ANSWER 17 OF 26 CA COPYRIGHT 2002 ACS
ΑN
    107:62036 CA
    Power generating optical filter
ΤI
```

```
PA
      Energy Conversion Devices, Inc., USA
SO
      Eur. Pat. Appl., 56 pp.
     CODEN: EPXXDW
DT
      Patent
LΑ
     English
     ICM H01L031-02
IC
     ICS H01L031-06
      52-2 (Electrochemical, Radiational, and Thermal Energy Technology)
CC
     Section cross-reference(s): 57
FAN.CNT 1
      PATENT NO.
                      KIND DATE
                                             APPLICATION NO. DATE
                              -----
      _____
                 A2
A3
     EP 218997
PΙ
                                             EP 1986-113548 19861002
                              19870422
     EP 218997
                              19890705
     EP 218997
                        В1
                              19930728
         R: AT, BE, CH, DE, ES, FR, GB, GR, IT, LI, LU, NL, SE
     CA 1268973 A1 19900515 CA 1986-519109 19860925 IN 166970 A 19900811 IN 1986-DE855 19860926 AT 92212 E 19930815 AT 1986-113548 19861002 JP 2575667 B2 19970129 JP 1986-241170 19861009 JP 08056007 A2 19960227 JP 1995-187457 19950724 JP 2752924 B2 19980518
     JP 2752924
                       B2 19980518
                       19851011
19851206
19861002
PRAI US 1985-786579
     US 1985-806232
     EP 1986-113548
                            19861002
     The title filter has a transparent substrate, a 1st substantially
AB
     transparent electrode disposed on at least designated areas of the
     substrate, a body of photovoltaic material disposed on the 1st
     electrode, and a 2nd substantially transparent electrode disposed on the
     body of photovoltaic material, to generate elec. power from
     absorbed selected wavelengths and transmit at least portions of selected
     wavelengths of unabsorbed incident light in the visible spectrum.
     Silicate or borosilicate glass, polymers (e.g., polyesters,
     polyimides, or polycarbonates), or laminated layers of these materials are
     used as the transparent substrate. Thin film semiconductors (amorphous
     F-doped hydrogenated Si, Si-Ge, CdS/CdTe, etc.) having p-i-n
     structure are used as the photovoltaic material; oxides of In,
     Sn, In-Sn, and Zn, etc., are used as the transparent electrodes. These
     filters are useful for motor vehicles or architectural building windows.
ST
     window glass solar cell
IT
     Windows
     Windshields
         (glass for, laminated with solar cells)
IT
     Photoelectric devices, solar
        (window glass with laminated)
L12 ANSWER 18 OF 26 CA COPYRIGHT 2002 ACS
AN
     106:123148 CA
TI
     Solar-cell module
IN
     Nakano, Akihiko; Takada, Hajime; Hibino, Takeshi; Yoshida, Manabu
PA
     Matsushita Electric Industrial Co., Ltd., Japan
so
     Jpn. Kokai Tokkyo Koho, 5 pp.
     CODEN: JKXXAF
DT
     Patent
LΑ
     Japanese
TC
     ICM H01L031-02
     52-2 (Electrochemical, Radiational, and Thermal Energy Technology)
     Section cross-reference(s): 38
FAN.CNT 1
     PATENT NO.
                   KIND DATE
                                            APPLICATION NO. DATE
```

IN

Ovshinsky, Stanford R.

ΡI JP 61280677 A2 19861211 JP 1985-122990 19850606 A solar-cell module has a solar cell AB formed on a substrate with blank edges, a protection film, a resin layer between the cell and the film, and a nonadhesive insulation sheet between the resin layer and the cell for absorbing mech. stress caused by the difference in thermal expansion. A thin-film CdS-CdTe or amorphous Si cell is used, and the sheet is a polymer having m.p. higher than that of the resin and is being larger than the cell. A CdS-CdTe cell was formed on an alkali-free borosilicate glass substrate with 6.5-mm-wide edges of the substrate left blank. A 50-.mu. poly(ethylene terephthalate) sheet, a 0.1-mm-thick anhydride-modified polyethylene layer, and a resin-coated Al protection film were stacked successively on the substrate. The assembly was inserted into a bag, and the bag was evacuated and heated to 135.degree. to seal the protection film to the blank edges by the atm. pressure. The output power of this module decreased 3% after 50 heat cycles between -20 and +80.degree. in a 90% relative humidity environment vs. 18% for a module without the sheet. Telluride cadmium solar cell module. solar cell module PET; cadmium sulfide solar cell module ΙT Photoelectric devices, solar (modules, with PET stress-absorbing sheets) 7440-21-3, Silicon, uses and miscellaneous IΤ RL: USES (Uses) (photoelec. solar-cell modules, amorphous, with PET stress-absorbing sheets) 1306-25-8, Cadmium telluride, uses and miscellaneous IT RL: USES (Uses) (solar-cell modules from junction of cadmium sulfide and, with PET stress-absorbing sheets) 1306-23-6, Cadmium sulfide, uses and miscellaneous IΤ RL: USES (Uses) (solar-cell modules from junction of cadmium telluride and, with PET stress-absorbing sheets) 25038-59-9, PET (polyester), uses and miscellaneous ΙT RL: USES (Uses) (solar-cell modules with stress-absorbing sheets ANSWER 19 OF 26 CA COPYRIGHT 2002 ACS L12AN 105:118218 CA Manufacture of solar cell TΙ Isozaki, Yasuto; Hasegawa, Hiroshi IN Matsushita Electric Industrial Co., Ltd., Japan PA SO Jpn. Kokai Tokkyo Koho, 3 pp. CODEN: JKXXAF DT Patent LΑ Japanese IC ICM H01L031-04 52-2 (Electrochemical, Radiational, and Thermal Energy Technology) CC Section cross-reference(s): 38 FAN.CNT 1 PATENT NO. KIND DATE APPLICATION NO. DATE ____ ----------PIJP 61111585 A2 19860529 JP 1984-232887 19841105 JP 05019836 B4 19930317 A depolymerizable polymer is added to CdS-CdCl2 and CdTe AΒ -CdCl2 mixts. to form pastes for solar cell manuf. The polymer is decompd. by heating after the application of the paste. Thus, a paste of CdS 60, CdCl2 6, poly(Me methacrylate) 3, and benzyl alc. 31% was screen printed on a glass substrate, heated at

400.degree. for 1 h, and at 690.degree. in N for 1 h to form a CdS film. A paste of cdre 60, CdCl2 0.3, poly(methacrylic acid) 3, and benzyl alc. 36.7% was screen printed on the sintered CdS film, heated at 400.degree. for 1 h, and at 620.degree. in N for 1 h to form a sintered CdTe film. A C-Ag electrode and a Ag or In electrode were then formed on the CdTe and CdS films, resp., to form a solar cell. The sintered layers showed no cracks and had accurate patterning, and the prepd. cell had an output voltage of 0.8 V. cadmium sulfide solar cell; telluride STcadmium solar cell; polymethyl methacrylate solar cell manuf Photoelectric devices, solar IT(cadmium sulfide-cadmium telluride, screen printing in manuf. of) IT 9011-14-7 25087-26-7 RL: USES (Uses) (in manuf. of cadmium sulfide-cadmium telluride solar cells) IT1306-25-8P, preparation RL: PREP (Preparation) (photoelec. solar cells from junctions of cadmium sulfide and, screen printing in manuf. of) ΙT 1306-23-6P, preparation RL: PREP (Preparation) (photoelec. solar cells from junctions of

cadmium